

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

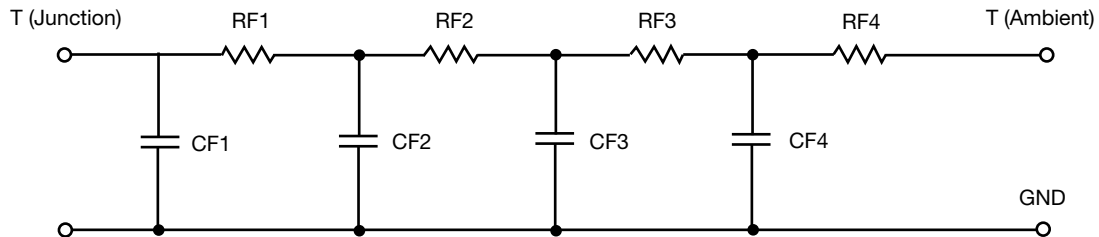


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	9.0993	1.6649	N/A
RT2	11.2693	1.4466	N/A
RT3	17.1948	3.1099	N/A
RT4	42.4366	1.9069	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	252.4424u	124.2532u	N/A
CT2	375.2537m	844.1844u	N/A
CT3	8.9592m	1.7439m	N/A
CT4	2.0618	1.1919m	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	5.7692	2.7648	N/A
RF2	18.3361	2.9681	N/A
RF3	14.3636	2.0929	N/A
RF4	41.5311	277.5440m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	91.9999u	110.1720u	N/A
CF2	4.0841m	211.3046u	N/A
CF3	156.9107m	1.4369m	N/A
CF4	1.8115	5.6854m	N/A

Note

N/A indicates not applicable

